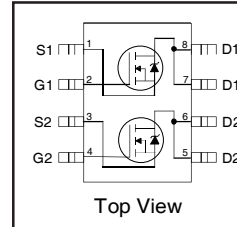


# AUIRF7303Q

HEXFET® Power MOSFET

## Features

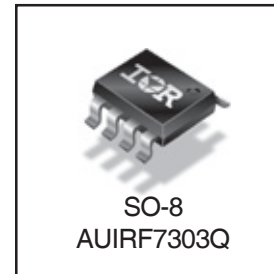
- Advanced Planar Technology
- Dual N Channel MOSFET
- Low On-Resistance
- Dynamic dV/dT Rating
- 175°C Operating Temperature
- Fast Switching
- Lead-Free, RoHS Compliant
- Automotive Qualified\*



$V_{(BR)DSS}$		<b>30V</b>
$R_{DS(on)}$ max.		<b>0.05Ω</b>
$I_D$		<b>5.3A</b>

## Description

Specifically designed for Automotive applications, this cellular design of HEXFET® Power MOSFETs utilizes the latest processing techniques to achieve low on-resistance per silicon area. This benefit combined with the fast switching speed and ruggedized device design that HEXFET power MOSFETs are well known for, provides the designer with an extremely efficient and reliable device for use in Automotive and a wide variety of other applications.



## Absolute Maximum Ratings

Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only; and functional operation of the device at these or any other condition beyond those indicated in the specifications is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions. Ambient temperature ( $T_A$ ) is 25°C, unless otherwise specified.

	Parameter	Max.	Units
$I_D @ T_A = 25^\circ\text{C}$	Continuous Drain Current, $V_{GS} @ 10\text{V}$	5.3	A
$I_D @ T_A = 70^\circ\text{C}$	Continuous Drain Current, $V_{GS} @ 10\text{V}$	4.4	
$I_{DM}$	Pulsed Drain Current ①	44	
$P_D @ T_A = 25^\circ\text{C}$	Power Dissipation	2.4	W
	Linear Derating Factor	0.02	W/°C
$V_{GS}$	Gate-to-Source Voltage	± 20	V
$E_{AS}$	Single Pulse Avalanche Energy ②	414	mJ
$E_{AS(Tested)}$	Single Pulse Avalanche Energy ⑤	1160	
dv/dt	Peak Diode Recovery dv/dt ③	1.6	V/ns
$T_J$ $T_{STG}$	Operating Junction and Storage Temperature Range	-55 to + 175	°C

## Thermal Resistance

	Parameter	Max.	Units
$R_{\theta JA}$	Junction-to-Ambient ④	62.5	°C/W

HEXFET® is a registered trademark of International Rectifier.

\*Qualification standards can be found at <http://www.irf.com/>


### Static Electrical Characteristics @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

	Parameter	Min.	Typ.	Max.	Units	Conditions
$V_{(BR)DSS}$	Drain-to-Source Breakdown Voltage	30	—	—	V	$V_{GS} = 0V, I_D = 250\mu A$
$\Delta V_{(BR)DSS}/\Delta T_J$	Breakdown Voltage Temp. Coefficient	—	0.03	—	V/ $^\circ\text{C}$	Reference to $25^\circ\text{C}, I_D = 1\text{mA}$
$R_{DS(on)}$	Static Drain-to-Source On-Resistance	—	—	0.05	$\Omega$	$V_{GS} = 10V, I_D = 2.7A$ ④
		—	—	0.08		$V_{GS} = 4.5V, I_D = 2.1A$ ④
$V_{GS(th)}$	Gate Threshold Voltage	1.0	—	3.0	V	$V_{DS} = V_{GS}, I_D = 100\mu A$
gfs	Forward Transconductance	5.6	—	—	S	$V_{DS} = 15V, I_D = 2.7A$
$I_{DSS}$	Drain-to-Source Leakage Current	—	—	1.0	$\mu A$	$V_{DS} = 24V, V_{GS} = 0V$
		—	—	25		$V_{DS} = 24V, V_{GS} = 0V, T_J = 125^\circ\text{C}$
$I_{GSS}$	Gate-to-Source Forward Leakage	—	—	-100	nA	$V_{GS} = 20V$
	Gate-to-Source Reverse Leakage	—	—	100		$V_{GS} = -20V$

### Dynamic Electrical Characteristics @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

	Parameter	Min.	Typ.	Max.	Units	Conditions
$Q_g$	Total Gate Charge	—	14	21	nC	$I_D = 2.7A$
$Q_{gs}$	Gate-to-Source Charge	—	1.5	2.3		$V_{DS} = 15V$
$Q_{gd}$	Gate-to-Drain ("Miller") Charge	—	4.4	6.6		$V_{GS} = 10V$ ④
$t_{d(on)}$	Turn-On Delay Time	—	2.9	—	ns	$V_{DD} = 15V$
$t_r$	Rise Time	—	6.2	—		$I_D = 2.7A$
$t_{d(off)}$	Turn-Off Delay Time	—	15	—		$R_G = 6.8\Omega$
$t_f$	Fall Time	—	7.8	—		$V_{GS} = 10V$ ④
$C_{iss}$	Input Capacitance	—	515	—	pF	$V_{GS} = 0V$
$C_{oss}$	Output Capacitance	—	217	—		$V_{DS} = 25V$
$C_{rss}$	Reverse Transfer Capacitance	—	90	—		$f = 1.0\text{MHz}$

### Diode Characteristics

	Parameter	Min.	Typ.	Max.	Units	Conditions
$I_S$	Continuous Source Current (Body Diode)	—	—	3.0	A	MOSFET symbol showing the integral reverse p-n junction diode. 
$I_{SM}$	Pulsed Source Current (Body Diode) ①	—	—	44		
$V_{SD}$	Diode Forward Voltage	—	—	1.0	V	$T_J = 25^\circ\text{C}, I_S = 2.7A, V_{GS} = 0V$ ④
$t_{rr}$	Reverse Recovery Time	—	26	39	ns	$T_J = 25^\circ\text{C}, I_F = 2.7A$
$Q_{rr}$	Reverse Recovery Charge	—	50	75	nC	$di/dt = 100A/\mu s$ ④

#### Notes:

- ① Repetitive rating; pulse width limited by max. junction temperature.
- ② Limited by  $T_{Jmax}$ , starting  $T_J = 25^\circ\text{C}$ ,  $L = 118\text{mH}$ ,  $R_G = 50\Omega$ ,  $I_{AS} = 2.7A$ ,  $V_{GS} = 10V$ . Part not recommended for use above this value.
- ③  $I_{SD} \leq 2.7A$ ,  $di/dt \leq 389A/\mu s$ ,  $V_{DD} \leq V_{(BR)DSS}$ ,  $T_J \leq 175^\circ\text{C}$ .
- ④ Pulse width  $\leq 400\mu s$ ; duty cycle  $\leq 2\%$ .
- ⑤ This value determined from sample failure population, starting  $T_J = 25^\circ\text{C}$ ,  $L = 118\text{mH}$ ,  $R_G = 50\Omega$ ,  $I_{AS} = 2.7A$ ,  $V_{GS} = 10V$ .
- ⑥ Surface mounted on FR-4 board,  $t \leq 10\text{sec.}$

**Qualification Information<sup>†</sup>**

<b>Qualification Level</b>		Automotive (per AEC-Q101) <sup>††</sup>	
		Comments: This part number(s) passed Automotive qualification. IR's Industrial and Consumer qualification level is granted by extension of the higher Automotive level.	
<b>Moisture Sensitivity Level</b>		SO-8	MSL1
<b>ESD</b>	Machine Model	Class M2 (+/- 150V) <sup>†††</sup> AEC-Q101-002	
	Human Body Model	Class H1A (+/- 500V) <sup>†††</sup> AEC-Q101-001	
	Charged Device Model	Class C5 (+/- 1500V) <sup>†††</sup> AEC-Q101-005	
<b>RoHS Compliant</b>		Yes	

† Qualification standards can be found at International Rectifier's web site: <http://www.irf.com/>

†† Exceptions (if any) to AEC-Q101 requirements are noted in the qualification report.

††† Highest passing voltage

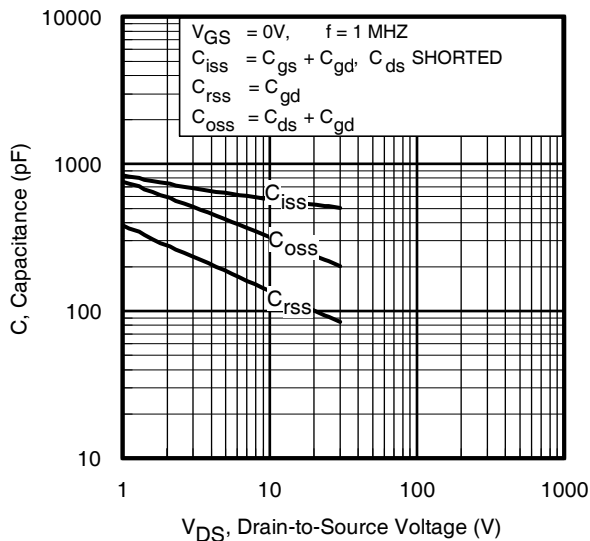
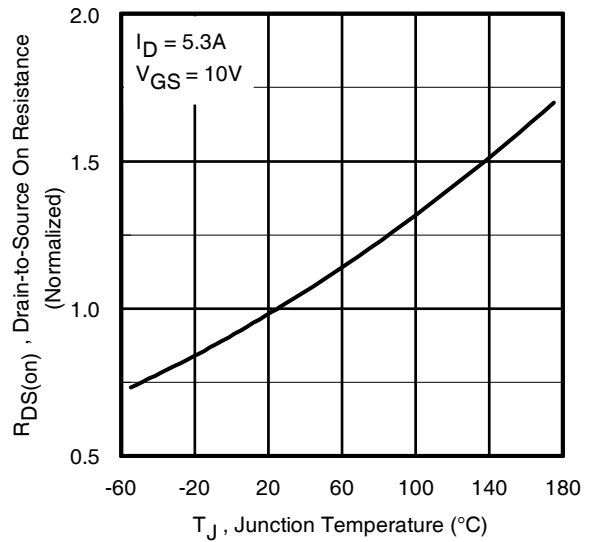
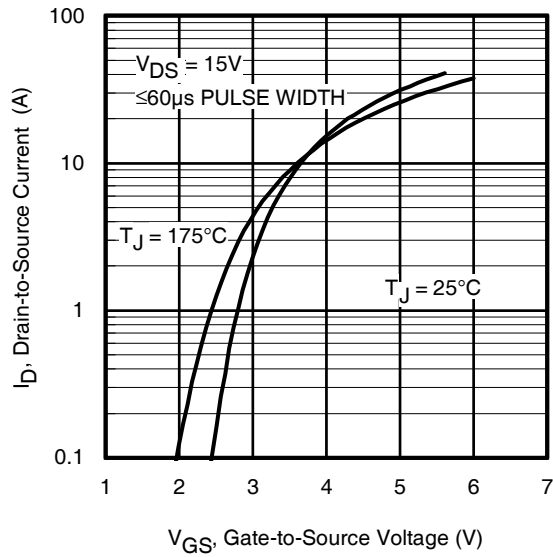
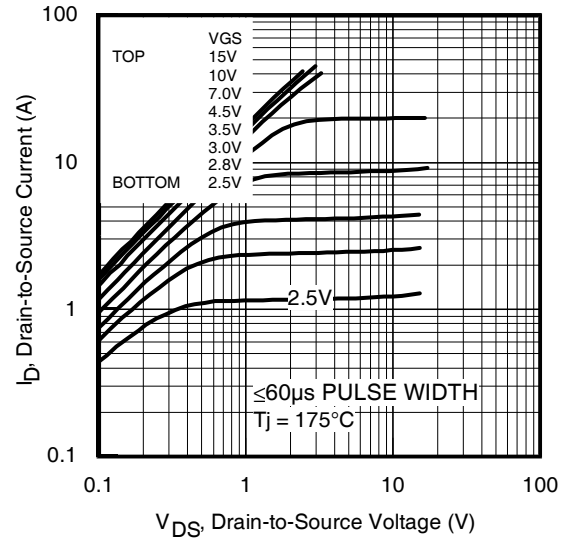
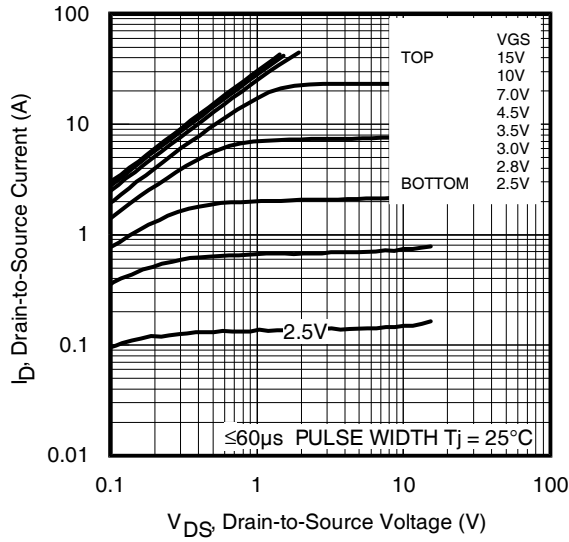


Fig 4. Normalized On-Resistance Vs. Temperature

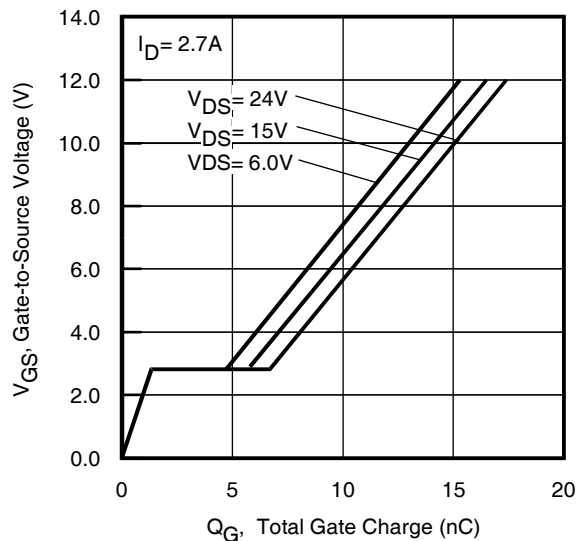


Fig 5. Typical Capacitance Vs. Drain-to-Source Voltage

Fig 6. Typical Gate Charge Vs. Gate-to-Source Voltage

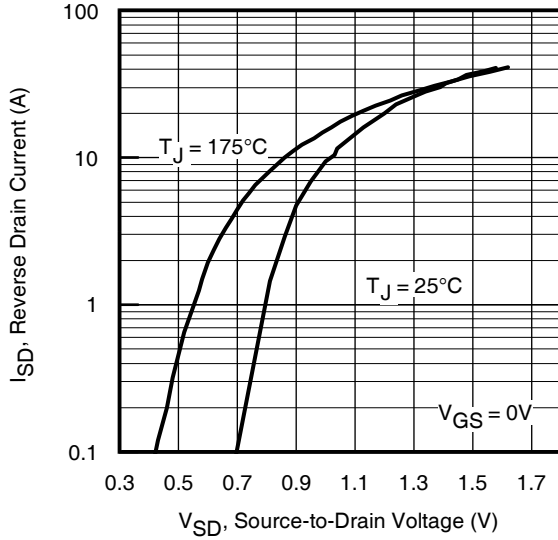


Fig 7. Typical Source-Drain Diode Forward Voltage

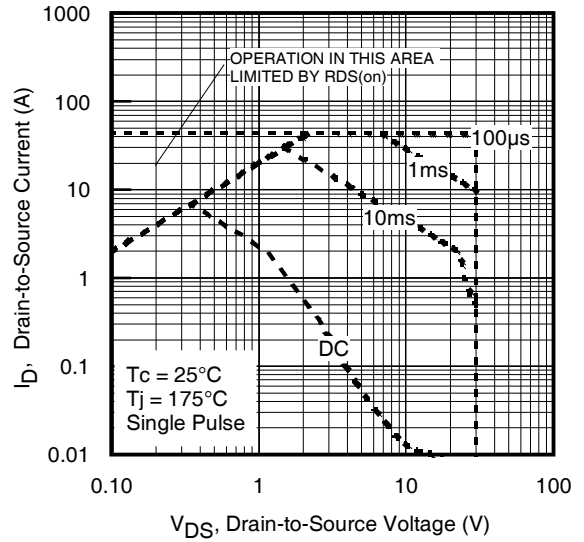


Fig 8. Maximum Safe Operating Area

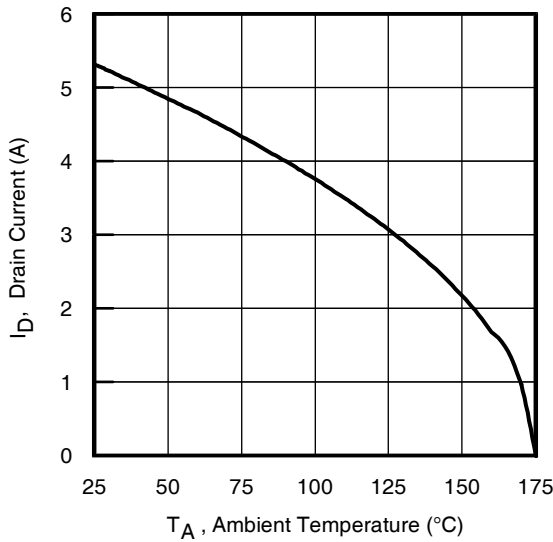


Fig 9. Maximum Drain Current Vs. Ambient Temperature

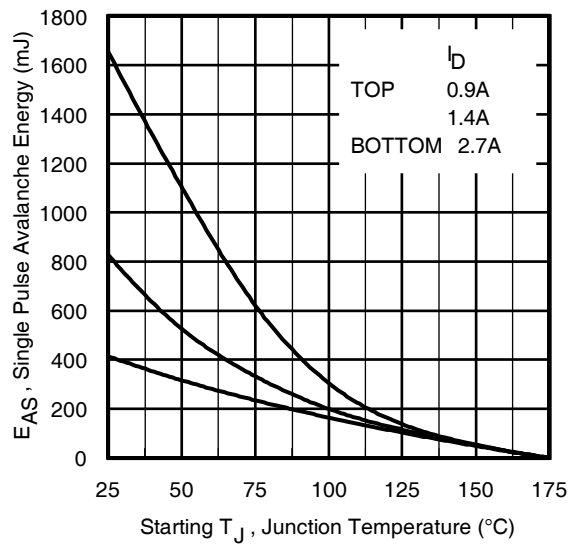


Fig 10. Maximum Avalanche Energy vs. Drain Current

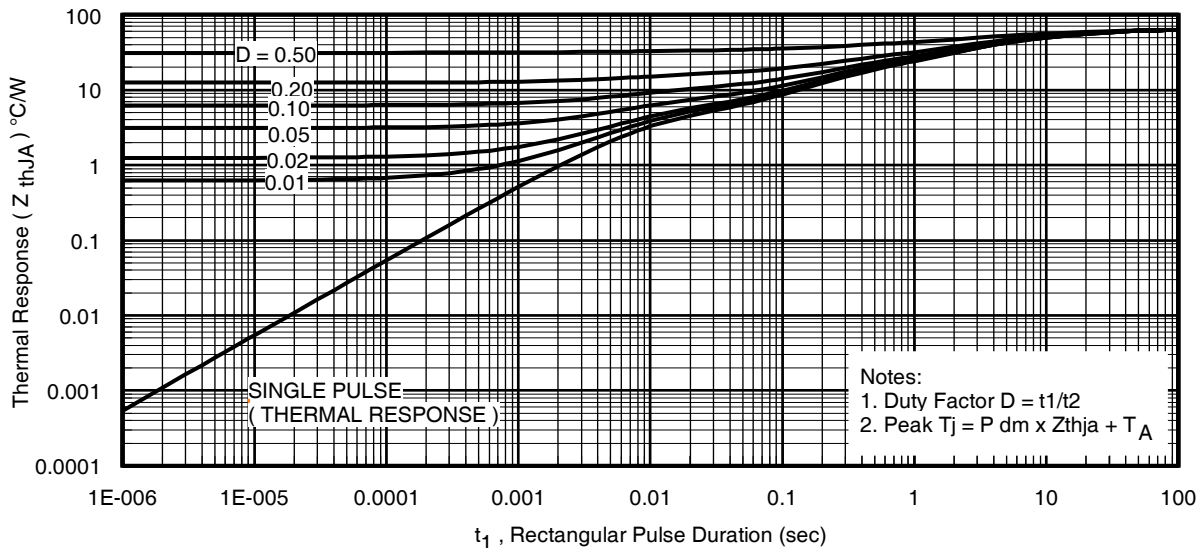
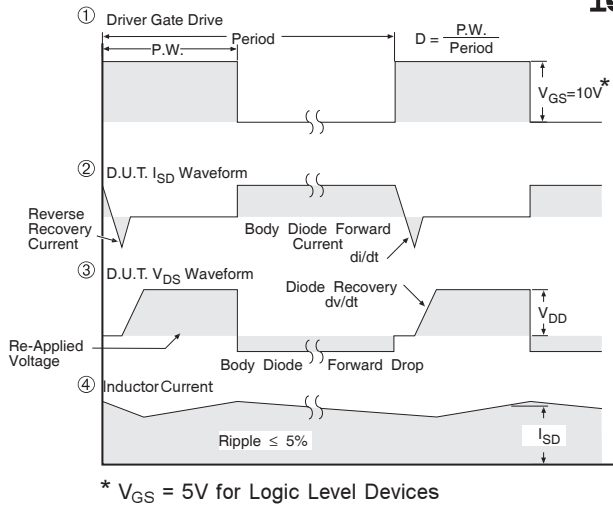
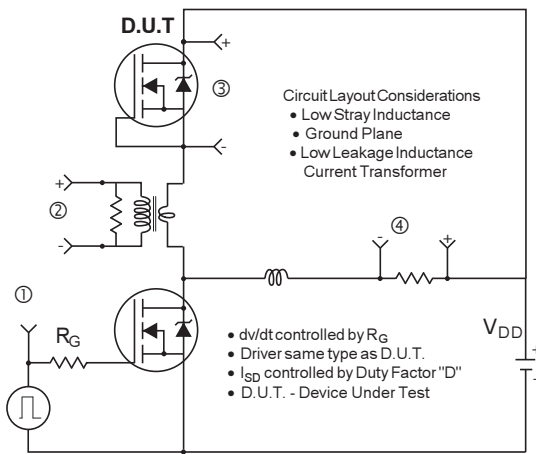
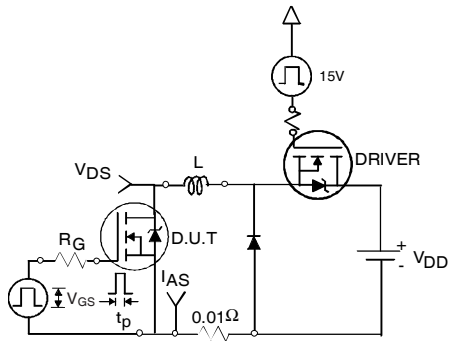


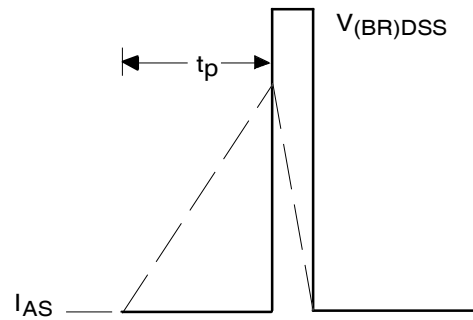
Fig 11. Maximum Effective Transient Thermal Impedance, Junction-to-Ambient



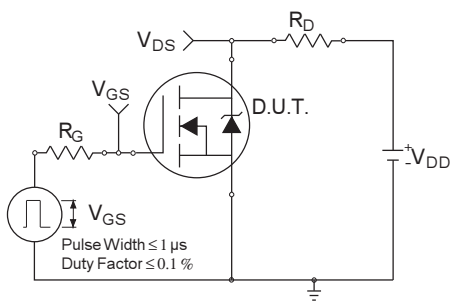
**Fig 12. Peak Diode Recovery dv/dt Test Circuit for N-Channel HEXFET® Power MOSFETs**



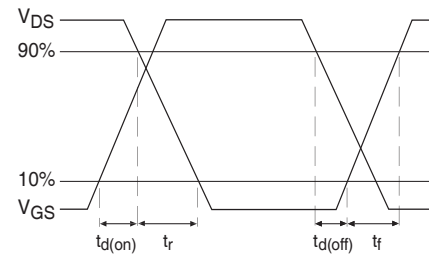
**Fig 13a. Unclamped Inductive Test Circuit**



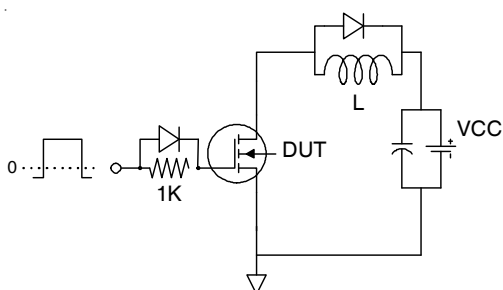
**Fig 13b. Unclamped Inductive Waveforms**



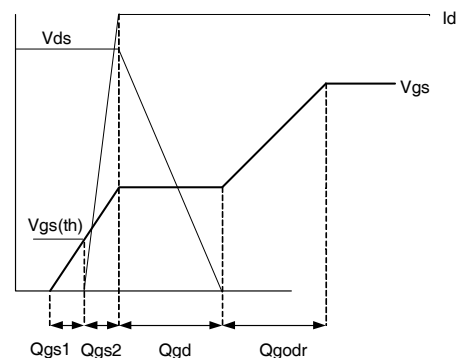
**Fig 14a. Switching Time Test Circuit**



**Fig 14b. Switching Time Waveforms**



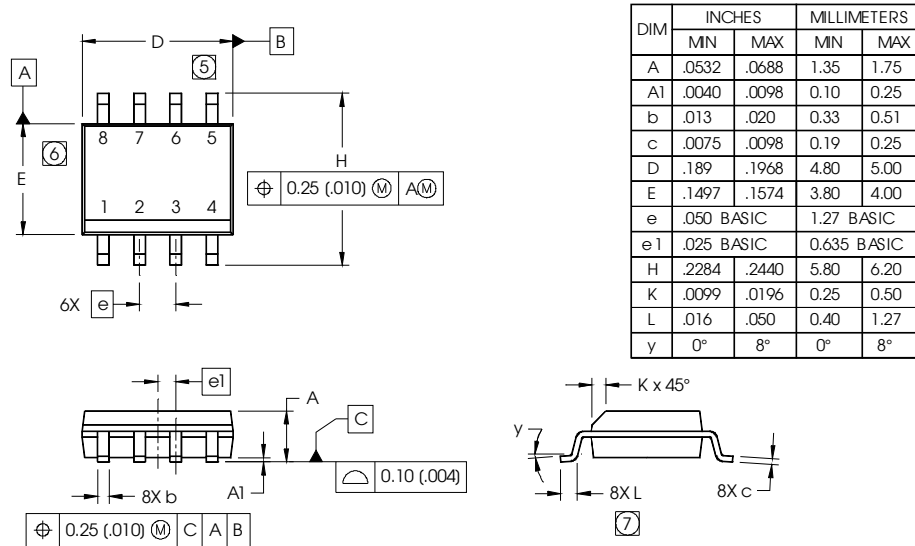
**Fig 15a. Gate Charge Test Circuit**



**Fig 15b. Gate Charge Waveform**

## SO-8 Package Outline

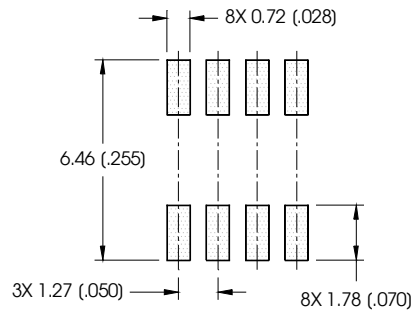
Dimensions are shown in millimeters (inches)



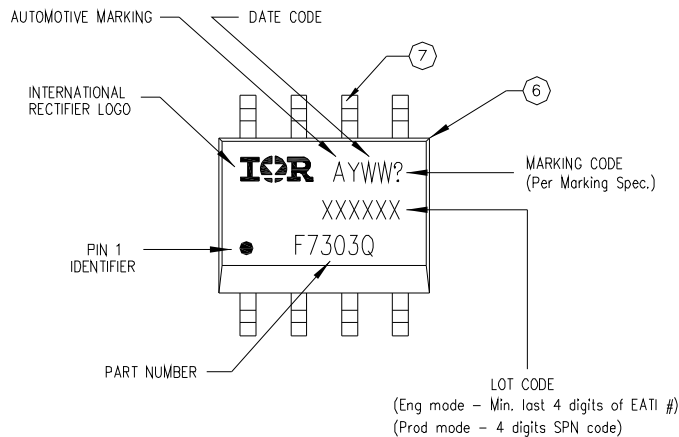
**NOTES:**

1. DIMENSIONING & TOLERANCING PER ASME Y14.5M-1994.
2. CONTROLLING DIMENSION: MILLIMETER
3. DIMENSIONS ARE SHOWN IN MILLIMETERS (INCHES).
4. OUTLINE CONFORMS TO JEDEC OUTLINE MS-012AA.
- ⑤ DIMENSION DOES NOT INCLUDE MOLD PROTRUSIONS. MOLD PROTRUSIONS NOT TO EXCEED 0.15 (.006).
- ⑥ DIMENSION DOES NOT INCLUDE MOLD PROTRUSIONS. MOLD PROTRUSIONS NOT TO EXCEED 0.25 (.010).
- ⑦ DIMENSION IS THE LENGTH OF LEAD FOR SOLDERING TO A SUBSTRATE.

**FOOTPRINT**



## SO-8 Part Marking

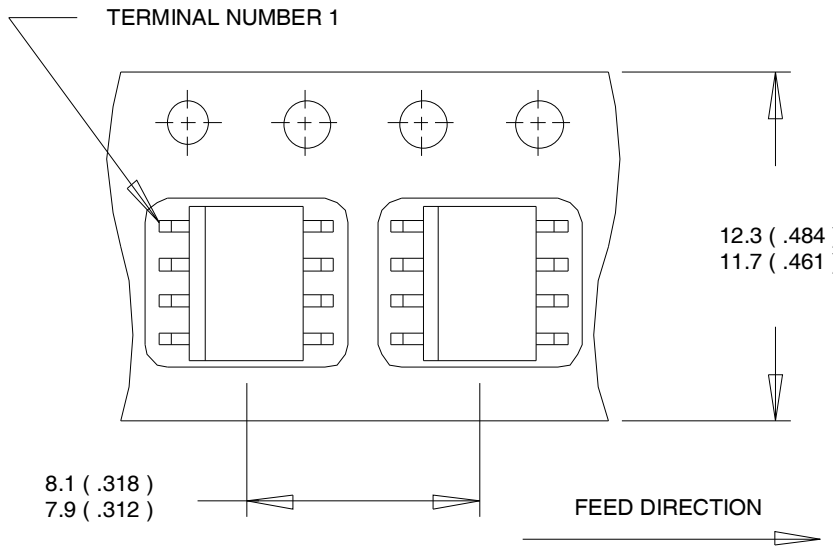


TOP MARKING (LASER)

**Note:** For the most current drawing please refer to IR website at <http://www.irf.com/package/>  
www.irf.com

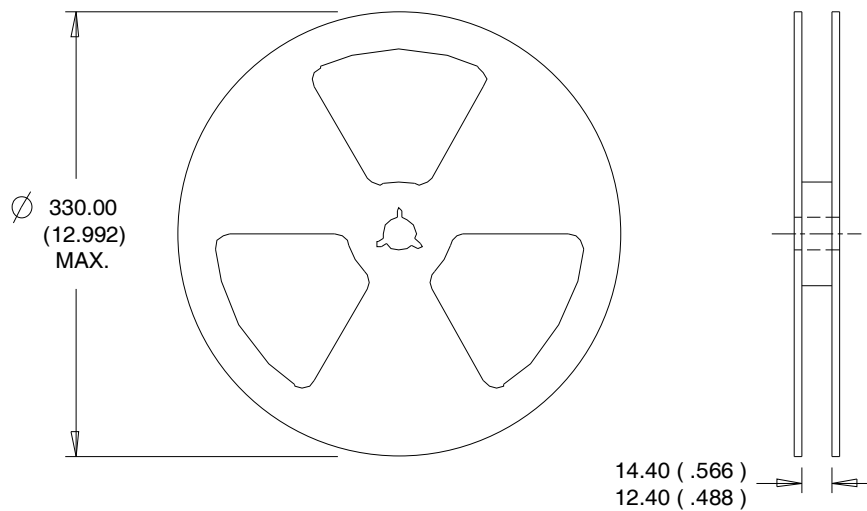
## SO-8 Tape and Reel

Dimensions are shown in millimeters (inches)



### NOTES:

1. CONTROLLING DIMENSION : MILLIMETER.
2. ALL DIMENSIONS ARE SHOWN IN MILLIMETERS(INCHES).
3. OUTLINE CONFORMS TO EIA-481 & EIA-541.



### NOTES :

1. CONTROLLING DIMENSION : MILLIMETER.
2. OUTLINE CONFORMS TO EIA-481 & EIA-541.



## Ordering Information

Base part number	Package Type	Standard Pack		Complete Part Number
		Form	Quantity	
AUIRF7303Q	SO-8	Tube	95	AUIRF7303Q
		Tape and Reel	4000	AUIRF7303QTR

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